



DESCRIPTION:

The JST04V-800SW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST04V-800SW snubberless triac is especially recommended for use on inductive loads. It can be driven directly through the MCU I/O port. Package SOT-223 is RoHS compliant.

MAIN FEATURES

PARAMETERS

Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-125	
Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$)	V_{DRM}	800	V
Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$)	V_{RRM}	800	V
RMS on-state current ($T_c=102^\circ\text{C}$)	$I_{T(RMS)}$	1	A
Non repetitive surge peak on-state current (full cycle, $t_p=20\text{ms}$, $T_j=25^\circ\text{C}$)	I_{TSM}	25	A
Non repetitive surge peak on-state current (full cycle, $t_p=16.6\text{ms}$, $T_j=25^\circ\text{C}$)		27.5	

I^2t value for fusing ($t_p=10\text{ms}$, T_j)



Peak pulse voltage ($T_j=25$; non-repetitive, off-state; FIG.8)	V_{pp}	3	kV
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ELECTRICAL CHARACTERISTICS ($T_j=25$ unless otherwise specified)

I_{GT}	$V_D=12V R_L=33$	- -	MAX.	10	mA
V_{GT}		- -	MAX.	1	V
V_{GD}	$V_D=V_{DRM} T_j=125$ $R_L=3.3K$	- -	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	-	MAX.	20	mA
				35	
I_H	$I_T=100mA$		MAX.	15	mA
dV/dt	$V_D=540V$ Gate Open $T_j=125$		MIN.	200	V/ μs
(dI/dt)c	(dV/dt)c=10V/ μs , $T_j=125$		MIN.	2.5	A/ms
t_{on}	$I_G=20mA I_A=200mA I_R=20mA$ $T_j=25$		TYP.	2.5	μs
t_{off}				25	

STATIC CHARACTERISTICS

V_{TM}	$I_{TM}=1.5A t_p=380\mu s$	$T_j=25$	1.35	V
V_{TO}	Threshold voltage	$T_j=125$	0.799	V
R_D	Dynamic resistance	$T_j=125$	151	m
I_{DRM}	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25$	5	μA
I_{RRM}		$T_j=125$	0.25	mA

THERMAL RESISTANCES

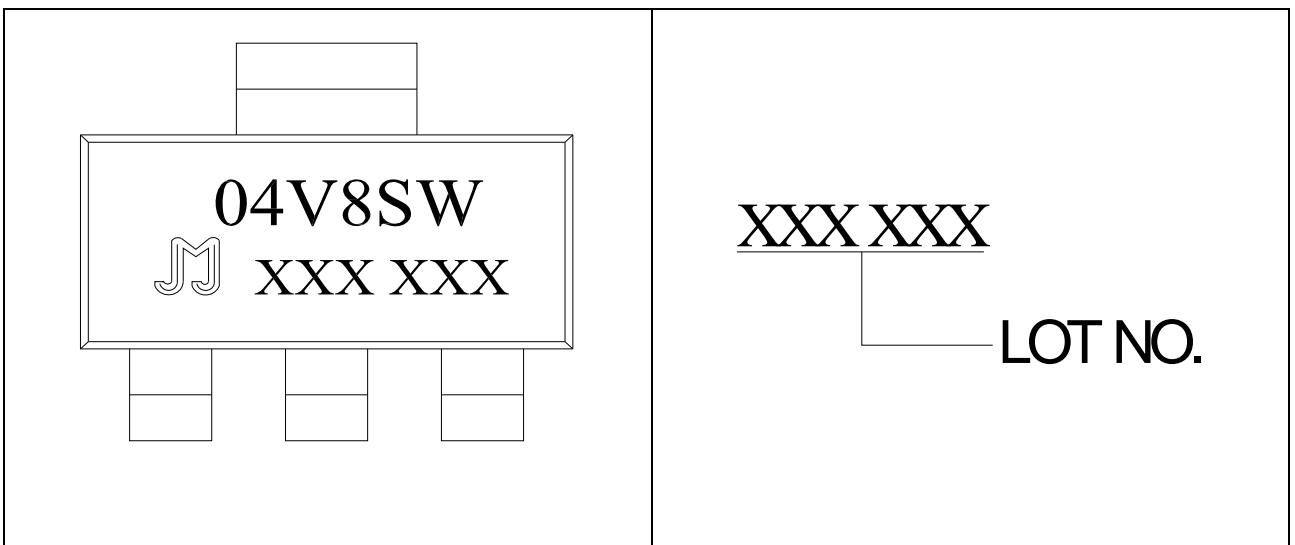
$R_{th(j-c)}$	junction to case (AC)	18	/W
$R_{th(j-a)}$	junction to ambient (AC)	160	/W



ORDERING INFORMATION

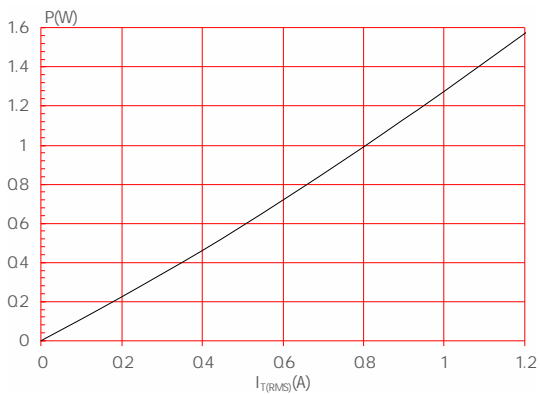
<u>JieJie Microelectronics Co., Ltd.</u>	<u>J</u>	<u>ST</u>	<u>04</u>	<u>V</u>	<u>-800</u>	<u>SW</u>
	Triacs	$I_{T(RMS)}:1A$				
			$V:SOT-223$			
					$800:V_{DRM}/V_{RRM}$	$SW:I_{GT1-3} 10mA$
					$800V$	

MARKING

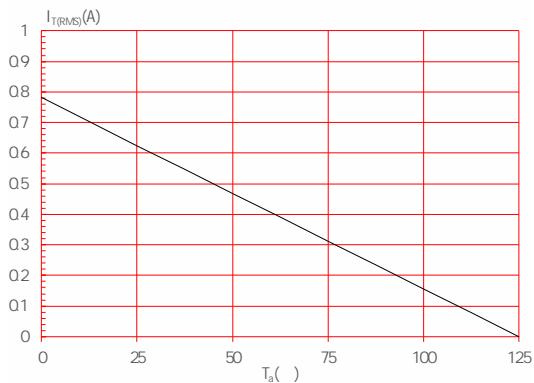




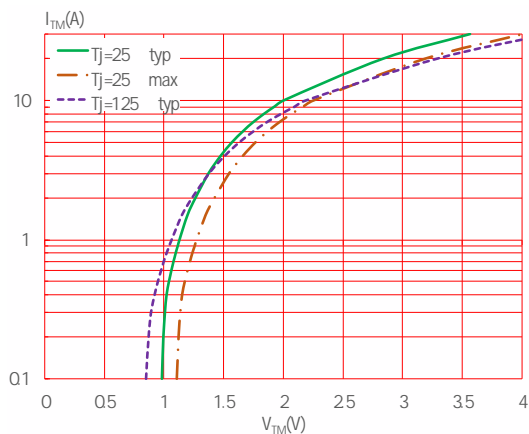
Maximum power dissipation versus RMS on-state current



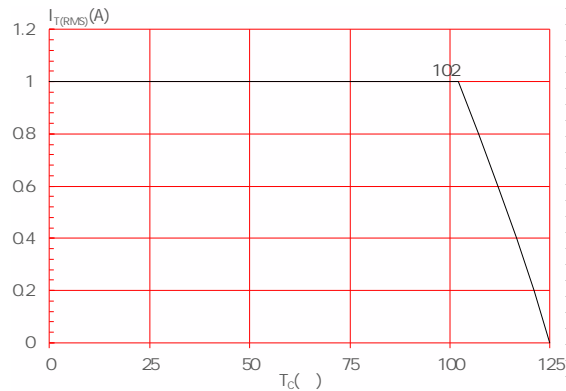
RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness:35μm)(full cycle)



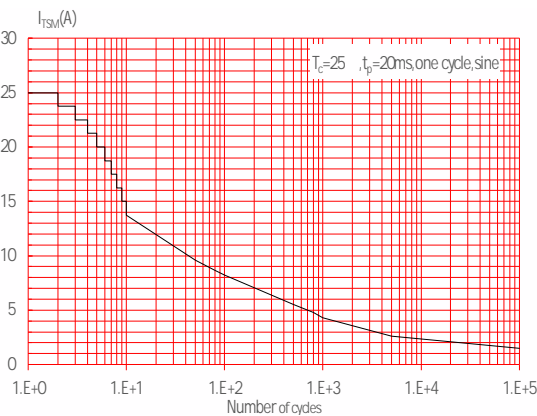
On-state characteristics



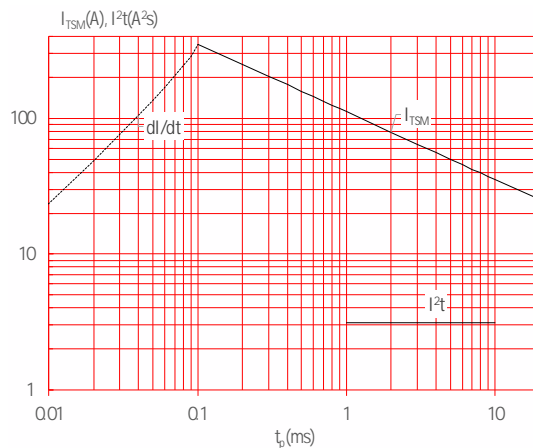
RMS on-state current versus case temperature



Surge peak on-state current versus number of cycles



Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I^2t ($di/dt < 100\text{A}/\mu\text{s}$)





Relative variations of gate trigger current, holding current and latching current versus junction temperature

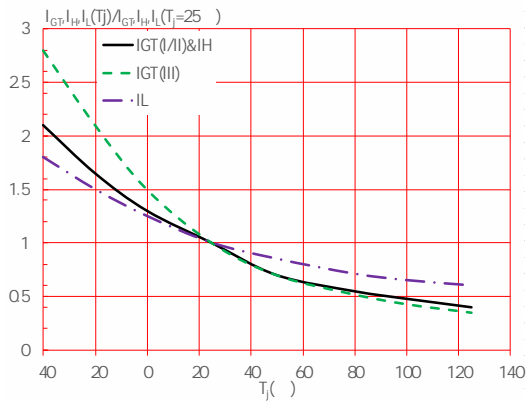
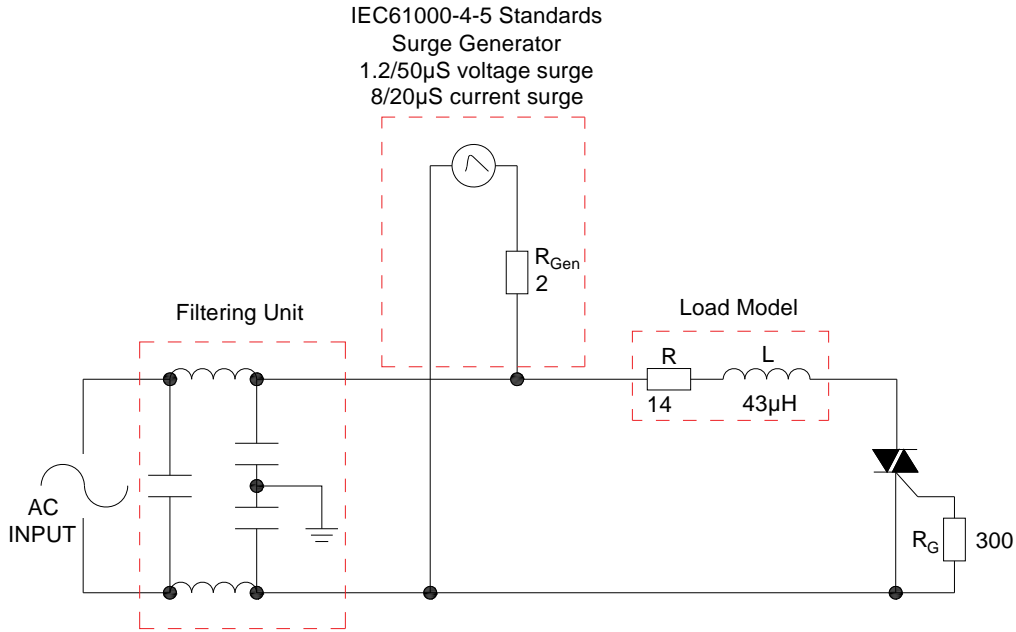
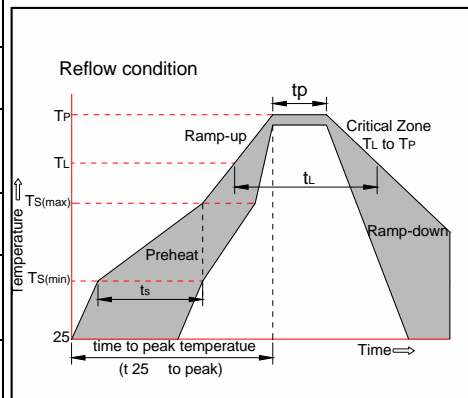


FIG.8 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see figure at right)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150
	-Temperature Max($T_{s(max)}$)	+200
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquidus Temp (T_L) to peak)		3 /sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3 /sec. Max
Reflow	-Temperature(T_L) (Liquidus)	+217
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)
Time within 5 of actual Peak Temp (t_p)		20-40secs.
Ramp-down Rate		6 /sec. Max
Time 25 to Peak Temp (T_p)		8 min. Max
Do not exceed		+260



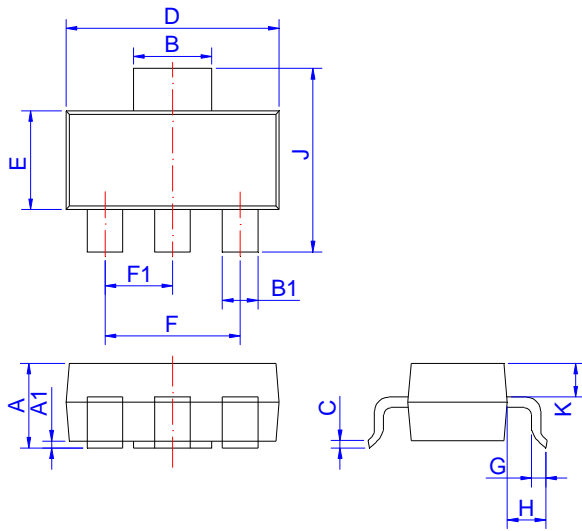


ORDERING INFORMATION

Date	Revision	Changes
Apr.11, 2023	A.1.0	Last updated
Jul.05, 2024	A.1.1	Renew dl/dt

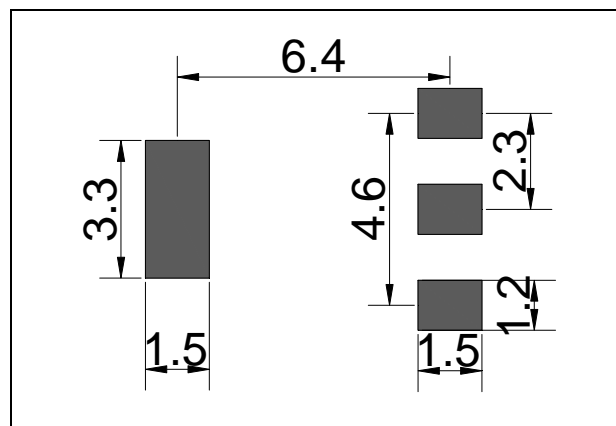


PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	1.5	1.6	1.8	0.059	0.063	0.071
A1	0.01	0.06	0.10	0.001	0.002	0.004
B	2.9	3.0	3.1	0.114	0.118	0.122
B1	0.6	0.7	0.8	0.024	0.028	0.031
C	0.22	0.26	0.32	0.009	0.010	0.013
D	6.3	6.5	6.7	0.248	0.256	0.264
E	3.3	3.5	3.7	0.130	0.138	0.146
F	4.4		4.8	0.173		0.189
F1	2.2		2.4	0.087		0.094
G	0.5		1.0	0.020		0.039
H	1.5	1.75	2.0	0.059	0.069	0.079
J	6.7	7.0	7.3	0.264	0.276	0.287
K	0.8	0.9	1.0	0.031	0.035	0.039

FOOTPRINT SOT 223 (dimensions in mm)





DELIVERY MODE


Ref.	Dimensions	+ A	+ A	9V
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